Carbon doping of superconducting magnesium diboride

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A bstract

We present details of synthesis optim ization and physical properties of nearly single phase carbon doped MgB₂ with a nominal stoichiom etry of Mg(B_{0.8}C_{0.2})₂ synthesized from magnesium and boron carbide (B₄C) as starting materials. The superconducting transition temperature is 22 K (17 K lower than in pure MgB₂). The temperature dependence of the upper critical eld is steeper than in pure MgB₂ with H_{c2} (10K) 9 T. Temperature dependent specic heat data taken in dierent applied magnetic elds suggest that the two-gap nature of superconductivity is still preserved for carbon doped MgB₂ even with such a heavily suppressed transition temperature. In addition, the anisotropy ratio of the upper critical eld for $T=T_c$ $\frac{2}{3}$ is 2. This value is distinct from 1 (isotropic) and also distinct from 6 (the value found for pure MgB₂).

Key words: magnesium diboride, carbon doping, synthesis, physical properties PACS: 74.70 Ad, 74.62 Dh, 74.25.-q

1 Introduction

Since the discovery of superconductivity in magnesium diboride at elevated ($T_{\rm c}$ 40 K) temperature [1,2], considerable progress has been achieved in material synthesis as well as in understanding of its physical properties [3,4,5,6,7,8]. From these initial days of research on superconducting M gB₂ many attempts were made to tailor the physical properties of the material to suite dierent needs as well as to explore the neighboring compounds in search of even higher $T_{\rm c}$ values.

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A number of groups undertook synthesis and characterization of (M g_1 $_z$ T $_z$)B $_2$ or M $_z$ ($_y$ M $_y$) $_z$ (T = transition m etal, Li, Be, Al; M = C, Si) m aterials. The agenda was multi-fold: to look for changes in T $_c$, to perform tests of the superconducting mechanisms in M $_z$ and to introduce additional pinning centers that could lead to higher critical current densities. Since many diborides crystallize in the same, hexagonal AlB $_z$ type of structure as M $_z$ and these compounds have been known and studied for decades [9] these substitutions initially were viewed as feasible. In spite of considerable e orts, substitutions in M $_z$ appeared to be dicult and in many cases unsuccessful or, at best, am biguous.

For magnesium site substitutions apparently only Alwas shown to enter the structure unambiguously [10,11,12,13,14] although in a limited concentration range. For boron site substitutions a number of attempts with dierent elements were made. Carbon substitution was reported in several publications [15,16,17,18,19,20]. Most of these attempts had elemental magnesium, boron and carbon as starting materials and the synthesis was performed at dierent pressures and tem peratures. The results varied considerably depending on the details of sample synthesis (for uniform ity we refer to the chemical formula written as M g ($B_{1 \times C_{\times}}$)₂): carbon solubility less then 1.25% was reported in [15], a two-step transition was observed in resistance measurements for nominal x = 0.1 [16], a solubility lim it of approximately x = 0.35 and shift of T_c 34.8 K for x = 0.03 was reported in [17], a T_c value of 34 K (at 2% of full diam agnetic signal, $T_c = 3K$) was measured by DC magnetization at 20 Oe in Mg($B_{0:8}C_{0:2}$)₂ (with no mention of solubility lim it) in [19], and a solubility limit of x 0:15 and $T_c(x = 0:15)$ 30 K was determined from magnetic measurements in [20].

One of the disculties associated with doping of M gB_2 m ay be the fact that the M gB_2 structure is robust and an intimate, atomic level, mixing of the dopant with the doped element before or in the process of synthesis is required to achieve the substitution. An interesting approach for carbon doping of M gB_2 was suggested by M ickelson et al. [18]. The starting materials for synthesis were elemental magnesium and boron carbide (B_4C) powder. The result of their synthesis was carbon doped M gB_2 as a majority phase and M gB_2C_2 as a minority phase. The T_c of the material was decreased by 7 K (down to 32 K) as seen by magnetization and resistance measurements. The resulting composition of the sample was estimated to be M $g(B_{0.9}C_{0.1})_2$. This initial study motivated us to attempt to optimize this synthetic route so as to eliminate the impurity phases and to perform a thorough investigation of the physical properties of the resulting material.

2 Experim ental

Sam ples of carbon doped M gB_2 for this study were synthesized in the form of sintered pellets following the procedure used for pure M gB_2 [3,4,21]. M agnesium lumps (99.9%) and B_4C powder (99% - A lfa sar) were sealed into tantalum tubes, sealed in quartz, placed into a heated box furnace and then (after the desired synthesis time) quenched to to room temperature. For all the samples except one (M $gB_2C_{0.5}$), the nominal stoichiometry was kept as M $g(B_{0.8}C_{0.2})_2$, i.e. M $g_5(B_4C)_2$. Synthesis temperature and time were varied system atically so as to optimize sample quality.

Powder X-ray di raction (XRD) measurements were made at room temperature using Cu K radiation in a Scintag di ractometer. A Sistandard was used for all runs. The Silines were removed from the X-ray di raction data leading to the apparent gaps in the powder X-ray data. The lattice parameters were obtained by thing the X-ray di raction spectra using Rietica software.

DC m agnetization m easurem ents were performed in Quantum Design MPMS-5 and MPMS-7 SQUID magnetometers. Four-probe AC resistance measurements were carried out in Quantum Design MPMS (with external LR-400 and LR-700 resistance bridges) and PPMS-9 units. Platinum wires were attached to the samples with Epotek H20E silver epoxy. Heat capacity data was collected on small pressed pellet samples using the PPMS-9 instrument in an applied eld of up to 9 T utilizing the relaxation technique.

3 Synthesis Optim ization

Figure 1a presents low eld magnetization data for a nominal Mg (B_{0:8}C_{0:2})₂ sam ple that was synthesized by heating for two hours at 600 C and then for two more hours at 700 C. This sample was made using the temperature/time schedule outlined by M ickelson et al. [18] and serves as a point of comparison. T_c of this sample (de ned via the onset of diam agnetism criterion) is and the superconducting fraction is signi cantly less than 100%. Tem perature dependent resistance for this sample is shown in the inset of Fig. 1a. The resistive transition temperature is consistent with the one determined by magnetic m easurem ents. The residual resistance ratio RRR = R (300K)/ R_0 R_0 de ned, in this case, as normal state resistance just above the transition). Powder X-ray di raction (see Fig. 1b) con m ed that the M g (Px Cx)2 phase was formed, however three other phases, M g2C3, M gB2C2 and rem nants of B_4C were also detected. Although the T_c of this sample is comparable with the one reported by M ickelson et al. [18], it appears to be poorly form ed and clearly requires optim ization.

The presence of unreacted B₄C in the X-ray pattern indicates that the reaction is probably not complete. Our next step in optim ization was to increase the reaction time to 24 hours and to perform synthesis at number of dierent tem peratures. Figure 2 presents powder X-ray di raction spectra for nominal M q $(B_{0.8}C_{0.2})_2$ sam ples synthesized for 24 hours at four dierent tem peratures: 750 C, 950 C, 1100 C, and 1200 C. W hereas the 750 C/24h sample contains a considerable amount of unreacted B_4C , traces of B_4C are much smaller for the 950 C/24h sample and are not visible in the XRD patterns of the 1100 C/24h and 1200 C/24h sam ples. In addition the amount of the two other impurity phases $(M g_2C_3)$ and $M gB_2C_2$ clearly decrease with an increase in synthesis temperature (see Fig. 2). The XRD patterns for 1100 C/24h and 1200 C/24h are very similar with respect to the apparent quantities of the im purity phases and present a signi cant im provem ent in purity in comparison to the 750 C/24h and 950 C/24h samples as well as to the sample reported in ref. [18] and data presented in Figure 1. The reactions carried out either at 1100 C or 1200 C appear to be approaching single phase.

Low eld DC magnetization and zero eld resistance data taken for the same set of sam ples also show an evolution of physical properties with the synthesis tem perature (Fig. 3). The superconducting transition for the 750 C/24h sam ple has an onset of the diam agnetic signal at 29 K but the transition, in fact, is very broad that probably reveals a distribution of transition temperatures within the sample probably due to chemical inhomogeneities. The transitions as seen in the M (T) data sharpen with the increase of the reaction temperature. The onset temperatures of the diam agnetic signal at the superconducting transition seem to decrease with the increase of the reaction temperature (see Fig. 3a, inset), however the temperatures at which the majority of the sam ple becomes superconducting (50% of the transition or maximum in QM =QT points) increase with the synthesis temperature for 950 C/24h - 1200 C/24h sam ples. Resistance data (Fig. 3b) manifest a similar trend e.g. the transition width decreases with the increase of reaction temperature. The transition tem peratures de ned using R = 0 criterion are 27, 19, 21, and 21.5 K for reaction temperatures of 750 C, 950 C, 1100 C, and 1200 C respectively.RRR decreases from 42 to 1.4 with the increase of the reaction temperature.

At this point we attempt (with some hesitancy) to estimate the room temperature resistivity or these samples. Very rough evaluation results in the values: 0.3 m -cm, 0.4 m -cm, 2 m -cm and 2 m -cm for 750 /24h, 950 C/24h, 1100 C/24h, and 1200 C/24h samples respectively. These numbers present the apparent resistivity, with an understanding that (i) the porosity of the sam - ples was not taken into account, (ii) no attempt was made to account for the possible contributions to the measured resistivity value from grain boundaries and impurity phases. Whereas the porosity of dierent samples prepared by the route described above can be considered as similar and allow for relative comparison of resistivities, we suggest that the possible elects of grain bound-

aries and impurity phases cannot be reliably accounted for within the available data on M g (B_{1 x} C_x)₂ com pounds and the m inority phases encountered in them . Only gross, order-of-magnitude, changes in apparent resistivity may, with some reservations, be taken as reecting the real evolution of transport properties. Keeping this warning in m ind we compare the apparent room tem perature resistivities of nearly single phase nom inal M g (B_{0.8}C_{0.2})₂ 1100 C/24h and 1200 C/24h compounds (2-3 m -cm) with those measured on pellets of pure M gB₂ (0.02-0.03 m -cm [22]) synthesized by similar technique using isotopically pure boron. In addition it should be mentioned that the apparent resistivity for M gB₂ synthesized using only 90% pure boron [21] was estimated 1.8, sim ilar to carbon doped to be 0.1 m -am (these samples have RRR 1100 C/24h and 1200 C/24h compounds). In addition, no literature reports on bulk, nom inally pure M gB₂ prepared by dierent techniques report a room tem perature resistivity value above several tenths of a m -cm . Based on these com parisons we conclude that our nearly single phase nom inal M g (B_{0.8}C_{0.2})₂ has a room temperature resistivity that appears to be signicantly higher than pure M qB2. Any conclusion beyond this fairly gross, qualitative statem ent runs the risk of over interpreting these data.

Since in a number of applications synthesis at lower temperatures can be bene cial and because the details of the reaction between elemental M g w ith B₁C are not known, we have checked to see if by perform ing this reaction at lower tem peratures but longer tim e we can obtain a material of similar or superior quality to the 1100 C/24h - 1200 C/24h samples. X-ray di raction patterns taken on samples reacted at 950 C for 3 hours, 24 hours and 5 days are shown in Fig. 4. For this reaction temperature the samples tend to improve with increasing reaction time, the intensities of the peaks corresponding to impurity phases monotonically decrease as reaction time increases from 3 h to 24 h to 5 days. The traces of unreacted B_4C are not seen for 950 C/5 days sample but M q₂C₃ and M qB₂C₂ are still clearly detectable. The quality of this sam ple (as inferred from XRD data) is approaching that of the sam ple synthesized at 1100 C or 1200 C for 24 hours (compare Figs. 2 and 4) but is still apparently inferior. Similarly, the low eld magnetization (see Fig. 5a) shows a gradual decrease of the width of the transition, indicating more homogenous samples, with the increase of the reaction time. Tem perature dependent resistance data (Fig. 5b) follow the same trend: transition width decreases with increases in the reaction time. The resistive transition temperatures (from R = 0) are 19, 19, and 18 K for the 3 h, 24 h, and 5 days reaction times. The RRR values decrease from 3 to 1.3 with the increase of the reaction time. On the other hand the transitions seen for all reaction times, even the 950 C/5 days sample, are all signi cantly broader than those seen for the 1100C/24 h and 1200 C/24h sam ples.

Based on the analysis of the two aforementioned data sets, the 1100 C/24h - 1200 C/24h reactions appear to optim ize the sample quality. Having this

in m ind we wanted to address one nal synthesis concem: would samples with nominal stoichiom etry of M g (B $_{0.8}$ C $_{0.2}$) $_2$ or M gB $_2$ C $_{0.5}$ be cleaner, i.e. do we get better samples with a M gB ratio of 1.2 or a M g:(B + C) ratio of 1.2? Both types of samples we synthesized following the 1100 C /24h schedule. Powder XRD spectra (Fig. 6) attest to the fact that the M g (B $_{0.8}$ C $_{0.2}$) $_2$ sample is cleaner. Low eld temperature dependent magnetization (Fig. 7) show that the transition temperatures of these two samples are virtually identical with a possibly slightly higher superconducting fraction found for the M g (B $_{0.8}$ C $_{0.2}$) $_2$ sample. Apparently the change to a M gB $_2$ C $_{0.5}$ initial stoichiom etry does not improve the purity of the phase or sharpness of the superconducting transition but does promote unwanted second phases.

To sum marize, the analysis of the three sets of samples discussed above (having reaction temperature, reaction time and the Mq: B4C ratio as variables) we nd that within the limitations of our synthesis route the M g (B_{0.8}C_{0.2})₂ sam ples reacted at 1100 C/24h - 1200 C/24h are the closest to being single phase sam ples and have sharper superconducting transition as seen in the tem perature dependent resistance and low eld m agnetization data. The transition for these samples has shifted down by $17 \text{ K} \text{ (T}_{c}$ 22 K) with respect to pure M qB_2 . The a-lattice parameter is approximately 12% smaller than for pure M gB₂ whereas the c-lattice parameter remains practically unchanged, a trend consistent with previous data [17,18,19,20]. The phase purity of these samples is better than that of the sam ple reported by M ickelson et al. [18] and clearly much better than the sample described in Figure 1. From the resistance data for the two sets of sam ples (with reaction temperature or reaction time being varied) it appears that the more phase-pure and homogenous samples have lower residual resistance ratios. This observation is opposite to what follows from the M attheissen's rule and is consistent with signi cant extrinsic contribution to the normal state resistance (and RRR) from other phases, grain boundaries, etc. that render attempts to use even sem iquantitative arguments based on normal state transport properties, e.g. the Testardi correlation [20], for such samples ambiguous. On the other hand, it is fairly clear that the intrinsic resistivity of the M g (B 0.8 C 0.2)2 sam ples is signi cantly higher than that of our pure M gB_2 sam ples [4,5,21].

A serious shortcom ing of carbon doping through this (M g + B₄C) reaction route is that determ ination of the carbon content in the nal sample appears to be a dicult and non-trivial task. In this report we will not attempt to address this issue for our samples and will leave this problem for future work. It should be noted that reliable and accurate quantitative determ ination of the carbon content (x) and/or consistent relation between three parameters: T_c , x and a-lattice parameter (since c is practically constant in all reports) cannot be found in the available literature [15,16,17,18,19,20]. As an aside note we would like to mention that we attempted to dope M gB₂ with silicon and phosphorus through (M g + B₆Si) and (M g + B₁₃P₂) synthesis routes.

These attempts were apparently not successful and resulted in multiphased compounds with no indication of doping into B site.

4 Physical Properties

Once the best available synthesis route was established, the nearly single phase 1100 C/24h sample was chosen for more detailed measurements of physical properties. Fig. 8 presents the temperature dependent resistance measurements taken in dierent appliedelds up to 9 T (an enlarged region near the superconducting transition in 0 - 9 T eld range is shown). Unlike the case of pure M qB₂ sam ples [4,5,6] practically no m agnetoresistance in the norm al state was observed. This is consistent with the very low residual resistance ra-1.6 for this sample and high estimated 0. the magnetotransport tio, RRR data (Fig. 8) together with eld and temperature dependent magnetization data (not shown here) were used to determ ine the upper critical eld for this sample (Fig. 9). The irreversibility line (Hirr) shown in this gure was determ ined from M (H) loops taken at di erent tem peratures. The irreversibility eld for this sam ple is quite low: it extrapolates to $H_{irr}(0)$ 2 T, which probably points to the fact that the carbon substitutions in the sample prepared from the M g and B₄C m ixture at 1100 C/24h conditions do not signi cantly increase the pinning. On the other hand, the H $_{c2}$ (T) slope for this sample is considerably steeper than in pure M gB_2 (see Fig. 9, inset), so although T_c of the carbon doped sample is approximately half of that for pure MgB2, the extrapolation H_{c2} (T ! 0) will give the value close to 16 T, sim ilar to that of high purity M gB2 [6]. Fig. 10 presents the critical current density for the 1100 C/24h sample as determined from magnetization loops using the Bean m odel [23]. The critical current densities are quite low, J_c (1.8K, H = 0) kA/cm², which is consistent with low pinning and the low lying irreversibility line (Fig. 9).

The heat capacity of the 1100 C/24h nom inal M g(B_{0.8}C_{0.2})₂ sam ple was measured on two dierent pressed pellets, from two separate batches in zero and 9 T applied eld. The specic heat jump at the superconducting transition is clearly seen (Fig. 11, inset) and the value of the jump is estimated as C 23 m J/m ol K. From 9 T measurements the electronic term in specic heat is extrapolated to 1.9 m J/m ol K² and the Debye temperature is estimated as $_{\rm D}$ 685 K. Both and $_{\rm D}$ values are lower than those accepted in the literature for pure M gB₂ sam ples [3,24,25,26] and have the same trend as seen experimentally in [20] and theoretically in [27]. At a gross level, the signicant decrease in T_c is consistent with lower and $_{\rm D}$ values for the carbon doped sample. The heat capacity dierence $_{\rm C_p}$ T = (C_p(H = 0) C_p(9T))=T as a function of temperature for the two dierent sam ples is plotted in Fig. 11. Both qualitatively and quantitatively the two sets of data are similar but it is worth

noting that there is some sample-to-sample and measurement-to-measurement variation.

One of the samples was chosen for more detailed measurements in dierent applied magnetic elds. The results of these measurements are presented in Fig. 12 in the form of $C_p = T = (C_p (H)) = C_p (9T) = T$ as a function of tem perature. The shift in the speci c heat jump at superconducting transition is a manifestation of the upper critical eld and is consistent with H_{c2} (T) m easured by other techniques (see stars in Fig. 9). The more interesting feature appears to be the low temperature shoulder in the excess of speciencheat seen in $(C_p(H = 0) C_p(9T))=T$ data below 10 K (also clearly seen for both sam ples in the previous gure). A similar feature was observed in pure M gB2 by di erent groups [24,25,26] and was interpreted as experimental evidence of a second, much lower energy, superconducting gap in MgB₂ [24,25,26,28]. There are other important similarities between heat capacity data of pure m agnesium diboride and the carbon doped sample: the low temperature feature disappears (lower gap is quenched) in small (0.5 T) applied eld and the $C_p = T_c$ value is substantially sm aller than expected for a BCS superconductors. These two peculiar results were shown to be present in pure M gB2 and to be consequences of the two-gap nature of superconductivity in this material. These similarities in heat the capacity data of pure and carbon doped magnesium diboride imply that despite the signi cantly suppressed T, and apparently large increase in resistivity, the novel double gap nature of supercondutivity persists in our nom inal M g (B $_{0.8}$ C $_{0.2}$) $_2$ sam ples. It is worth noting whereas there have been estimates of T_c 20 K for "isotropic" (single gap) M qB₂ [29,30] the case we seem to nd for our nom inal M q ($B_{0.8}$ C $_{0.2}$)₂ appears to be quite di erent with two distinct gaps. Further research will be required to con m this initial observation but, as it currently stands, this nding requires that the two superconducting gaps survive quite dram atic perturbations.

Finally, the anisotropic upper critical eld for carbon doped M gB_2 was evaluated from tem perature dependent magnetization measurements following the procedure outlined in [7,8]. Although the feature corresponding to $T_{c2}^{\,m}$ in (H) in (QM = QT) j_{i} for this sample was slightly broader than for pure M gB_2 it was possible to trace H $_{c2}^{\,m}$ above 12 K (see Fig. 13). The anisotropy of H $_{c2}$ at $\frac{2}{3}T_c$ is close to 2, i.e. carbon doped M gB_2 has apparently less anisotropic H $_{c2}$ than pure compound that may be a result of distortions in the Fermi surface and require additional theoretical/band-structure studies.

5 Conclusions

The synthesis of carbon doped magnesium diboride from magnesium and boron carbide (B_4C) with a nominal stoichiom etry of Mg($B_{0.8}C_{0.2}$)₂ was opti-

m ized and resulted in nearly single phase material with T_c 22 K. Sam ples obtained by this route have an upper critical eld of 9 T at 10 K and the slope of H_{c2} (T) is much steeper than for pure M_{c2} The sample has moderate J_c values pointing out that carbon introduced in the lattice via this synthetic route does not increase pinning signicantly. The specic heat data taken in dierent applied elds suggest that the two gap superconductivity is preserved in the M_{c2} G_{c2} sample despite the heavily suppressed G_{c2} in addition whereas there is a signicant G_{c2} anisotropy (2 for G_{c2}), it is reduced from the anisotropy found in pure G_{c2}

6 A cknow ledgem ents

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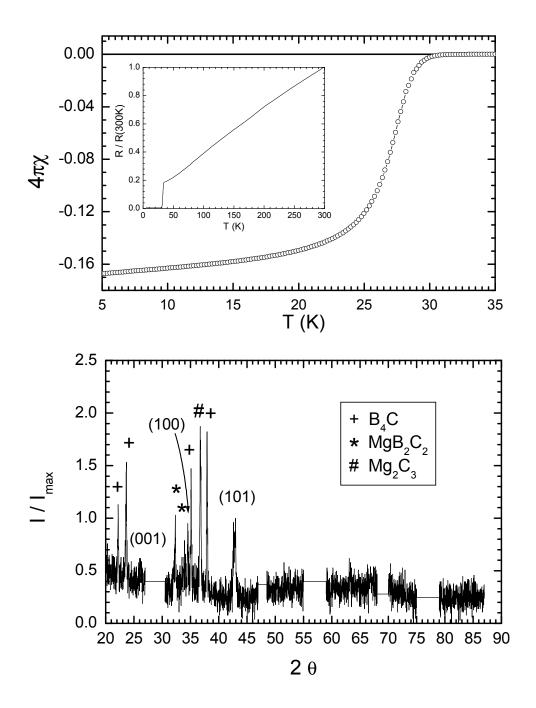


Fig. 1. (a) tem perature dependent m agnetic susceptibility for M g (B $_{0.8}$ C $_{0.2}$) $_2$ sam ple synthesized for 2 h at 600 C and then for 2 h at 700 C taken at H = 50 O e, ZFC - warming, insert - tem perature dependent resistance measured in zero applied eld; (b) powder X-ray diraction pattern for the same sample. Numbers in parentheses - (hkl) for M g (B $_1$ x C $_x$) $_2$, symbols mark peaks from dierent in purity phases.

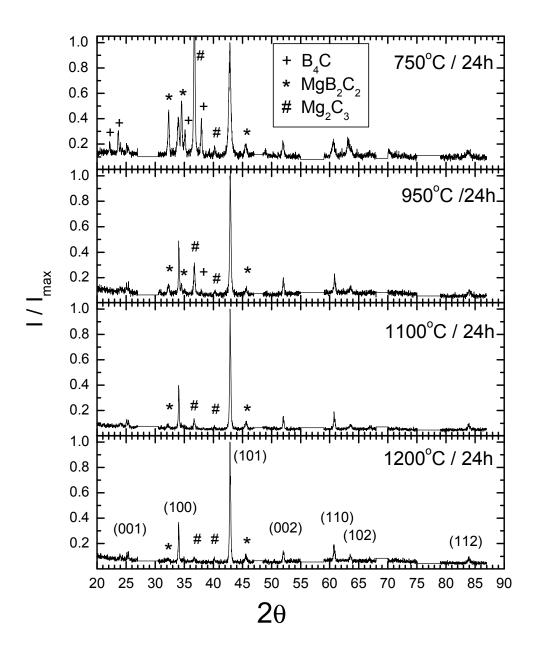


Fig. 2.Pow der X -ray di raction patterns for nom inal M g (B $_{0.8}$ C $_{0.2}$) $_2$ sam ples synthesized for 24 hours at 750 C, 950 C, 1100 C, and 1200 C. Num bers in parentheses in bottom panel-(hkl) for M g (B $_1$ x C $_x$) $_2$, sym bols m ark peaks from di erent in purity phases: crosses -B $_4$ C, asterisks -M gB $_2$ C $_2$, pound signs -M $_2$ C $_3$.

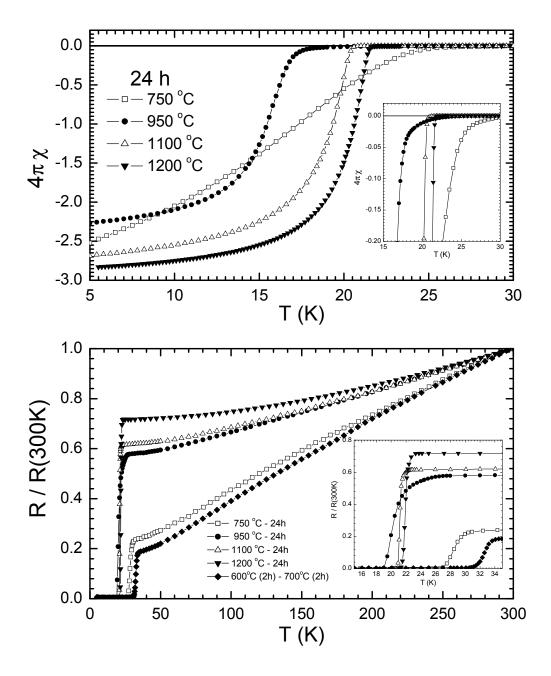


Fig. 3. (a)Tem perature dependent magnetic susceptibility for nominal Mg(B $_{0.8}$ C $_{0.2}$) $_2$ samples synthesized for 24 hours at 750 C, 950 C, 1100 C, and 1200 C taken at H = 50 Oe, ZFC -warming. Inset: expanded tem perature range near T $_c$. (b)Tem perature dependent, normalized resistance for the same set of samples plus reference sample (see text). Inset: expanded tem perature range near T $_c$.

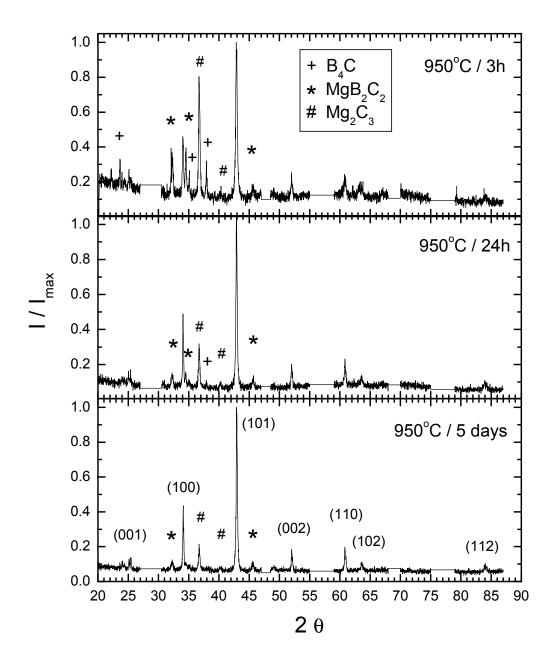


Fig. 4. Pow der X -ray di raction patterns for nom inal M g(B $_{0.8}$ C $_{0.2}$) $_2$ sam ples synthesized at 950 C for 3 h, 24 h, and 5 days. Num bers in parentheses in bottom panel – (hkl) for M g(B $_{1 \text{ x}}$ C $_{\text{x}}$) $_2$, symbols m ark peaks from di erent im purity phases.

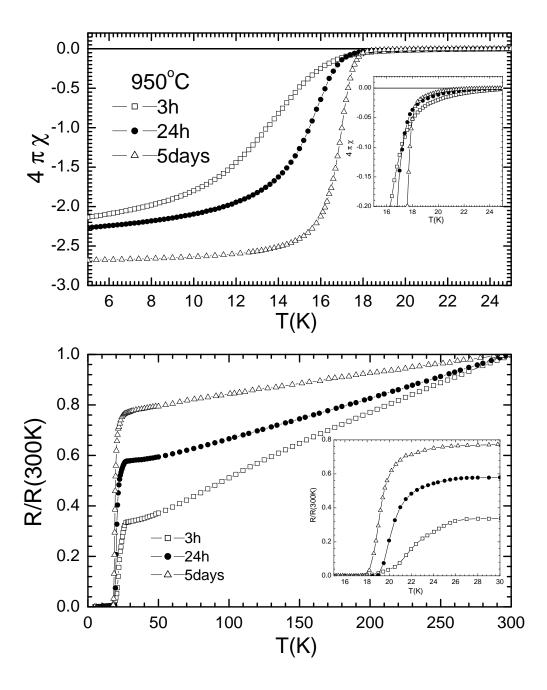


Fig. 5. (a)Tem perature dependent magnetic susceptibility for nominal Mg(B $_{0:8}$ C $_{0:2}$) $_2$ samples synthesized at 950 C for 3 h, 24 h, and 5 days. (b)Tem perature dependent normalized resistance for the same set of samples. Inset: expanded tem perature range near T $_{\text{C}}$.

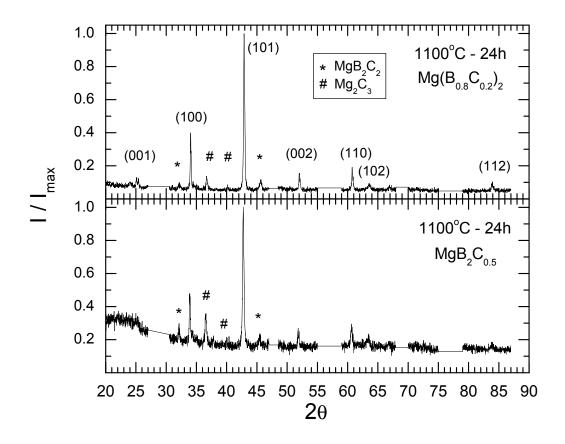


Fig. 6. Powder X-ray di raction patterns for nom inalM g(B $_{0:8}$ C $_{0:2}$) $_2$ and M gB $_2$ C $_{0:5}$ sam ples synthesized at 1100 C for 24 h. Numbers in parentheses upper panel – (hkl) for M g(B $_1$ x C $_x$) $_2$, symbols m ark peaks from di erent in purity phases: crosses –B $_4$ C, asterisks –M gB $_2$ C $_2$, pound signs –M g $_2$ C $_3$.

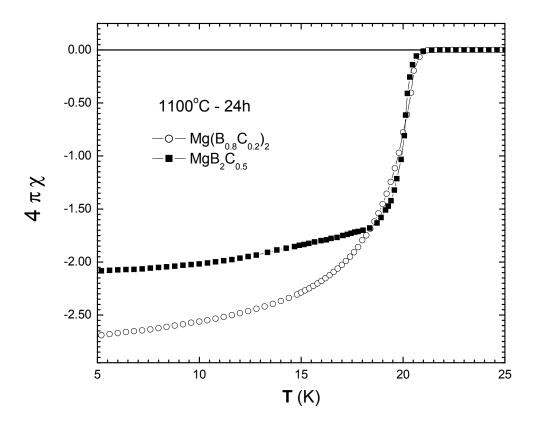


Fig. 7. Tem perature dependent m agnetic susceptibility (H = 500e, ZFC -w arm ing) for nom inal M g (B $_{0.8}$ C $_{0.2}$) $_2$ and M gB $_2$ C $_{0.5}$ sam ples synthesized at 1100 C for 24 h.

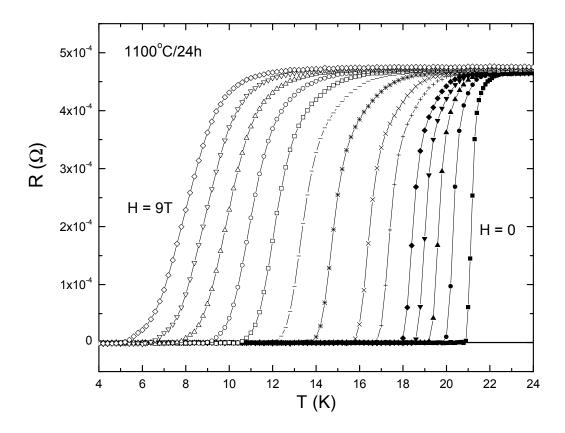


Fig. 8. Tem perature dependent resistance for 1100 C/24h sample in applied magnetic eld (elds from right to left: 0,025,0.5,0.75,1,1.5,2,3,4,5,6,7,8,9 T). Region near the transition shown.

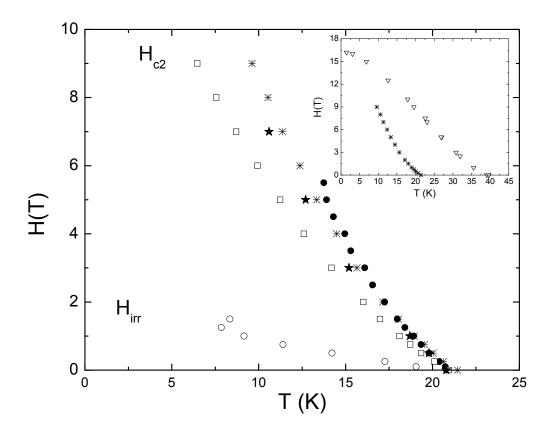


Fig. 9. Upper critical eld and irreversibility line for M g (B $_{0.8}$ C $_{0.2}$) $_2$ | 1100 C /24h sam ple. For H $_{c2}$: lled circles – from m agnetization, asterisks – from onset criterion of m agnetotransport data, squares – from R = 0 criterion of m agnetotransport data and stars – from heat capacity. Inset: comparison of H $_{c2}$ for pure M gB $_2$ [6] (open triangles) and carbon doped sam ple.

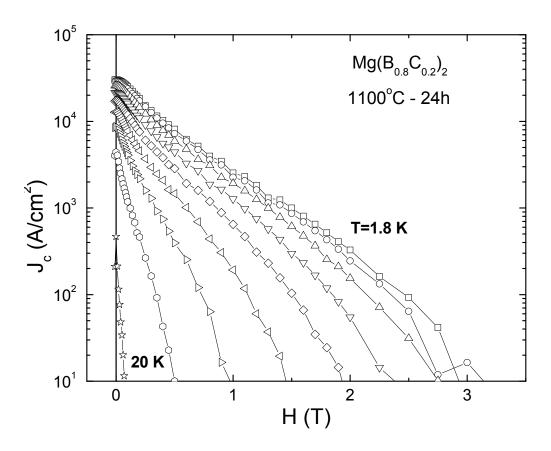


Fig. 10.C ritical current density for M g (B $_{0.8}$ C $_{0.2}$) $_2$ | 1100 C /24h sam ple as inferred from m agnetization loops. Tem peratures, from right to left: 1.8, 3, 5, 7.5, 10, 12.5, 15, 17.5, 20K .

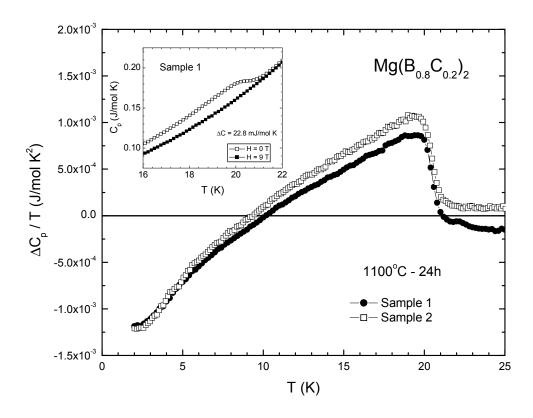


Fig.11.Heat capacity di erence C $_p$ =T = (C $_p$ (H = 0) C $_p$ (9T))=T as a function of tem perature for two di erent M g (B $_{0.8}$ C $_{0.2}$) $_2$ | 1100 C /24h sam ples. Inset: C $_p$ (T) data for H = 0 and H = 9 T in the region near T $_c$.

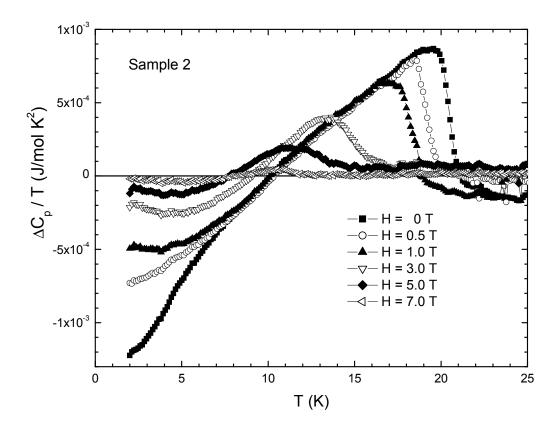


Fig. 12. Heat capacity di erence $C_p=T=(C_p(H))$ $C_p(9T))=T$ as a function of temperature for M $g(B_{0:8}C_{0:2})_2$ | 1100 C/24h sample taken for di erent applied elds.

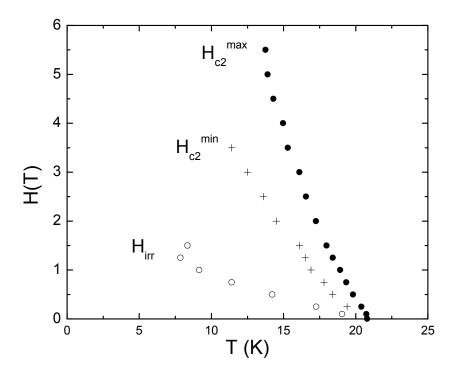


Fig. 13. A nisostropic H $_{\rm c2}$ and irreversibility line H $_{\rm irr}$ curves for M g (B $_{\rm 0.8}$ C $_{\rm 0.2}$) $_2$ | 1100 C/24h sam ple.